SN75976A DGG or DL

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Improved Speed and Package Replacement
for the SN75LBC976

- Designed to Operate at up to 20 Million Data Transfers per Second (Fast-20 SCSI)
- Nine Differential Channels for the Data and Control Paths of the Small Computer Systems Interface (SCSI) and Intelligent Peripheral Interface (IPI)
- SN75976A Packaged in Shrink Small-Outline Package with 25-Mil Terminal Pitch (DL) and Thin Shrink Small-Outline Package with 20-Mil Terminal Pitch (DGG)
- SN55976A Packaged in a 56-Pin Ceramic Flat Pack (WD)
- Two Skew Limits Available
- ESD Protection on Bus Terminals Exceeds 12 kV
- Low Disabled Supply Current 8 mA Typ
- Thermal Shutdown Protection
- Positive- and Negative-Current Limiting
- Power-Up/Down Glitch Protection

description

The SN75976A is an improved replacement for industry's first 9-channel **RS-485** the transceiver — the SN75LBC976. The A version offers improved switching performance, a smaller package, and higher ESD protection. The SN75976A is offered in two versions. The '976A2 skew limits of 4 ns for the differential drivers and 5 ns for the differential receivers complies with the recommended skew budget of the Fast-20 SCSI standard for data transfer rates up to 20 million transfers per second. The '976A1 supports the Fast SCSI skew budget for 10 million

S	N55970 (TOP \	
GND [BSR [1 2	56] CDE2 55] CDE1
CRE [3	54 CDE0
1A [4	53 9B+
1DE/RE [2A [5 6	52 9B- 51 8B+
2DE/RE	-	51 8B+ 50 8B-
3A [8	49 7B+
3DE/RE	9	48 🛛 7B-
<u>4</u> A	10	47 6B+
4DE/RE	11	46 6B-
	12	45 V _{CC}
GND [GND [13 14	44 GND 43 GND
GND [14	43 GND 42 GND
GND [16	41 GND
GND [1	40 GND
V _{CC}	18	39 🛛 V _{CC}
5A [19	38] 5B+
5DE/RE	20	37 🛛 5B-
<u>6A</u>	21	36 4B+
6DE/RE	22 23	35 4B- 34 3B+
7A [7DE/RE [23 24	34 3B+ 33 3B-
	25	32 3B=
8DE/RE	26	31 2B-
9A [27	30 1B+
9DE/RE	28	29 1B-

Terminals 13 through 17 and 40 through 44 are connected together to the package lead frame and signal ground.

transfers per second. The skew limit ensures that the propagation delay times, not only from channel-to-channel but from device-to-device, are closely matched for the tight skew budgets associated with high-speed parallel data buses.

The patented thermal enhancements made to the 56-pin shrink small-outline package (SSOP) of the SN75976 have been applied to the new, thin shrink, small-outline package (TSSOP). The TSSOP package offers even less board area requirements than the SSOP while reducing the package height to 1 mm. This provides more board area and allows component mounting to both sides of the printed circuit boards for low-profile, space-restricted applications such as small form-factor hard disk drives.



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description (continued)

In addition to speed improvements, the '976A can withstand electrostatic discharges exceeding 12 kV using the human-body model, and 600 V using the machine model of MIL-PRF-38535, Method 3015.7 on the RS-485 I/O terminals. This is six times the industry standard and provides protection from the noise that can be coupled into external cables. The other terminals of the device can withstand discharges exceeding 4 kV and 400 V respectively.

Each of the nine channels of the '976A typically meet or exceed the requirements of EIA RS-485 (1983) and ISO 8482-1987/TIA TR30.2 referenced by American National Standard of Information (ANSI) Systems, X3.131-1994 (SCSI-2) standard, X2.277-1996 (Fast-20 Parallel Interface), and the Intelligent Peripheral Interface Physical Layer-ANSI X3.129-1986 standard.

The SN75976A is characterized for operation over an ambient air temperature range of 0°C to 70°C. The SN55976A is characterized for operation over an ambient air temperature range of -55° C to 125° C.

T.		Limit s)		PACKAGE [†]	
TA	Driver	Receiver	TSSOP (DGG)	SSOP (DL)	CERAMIC FLAT PACK (WD)
000 to 7000	8	9	SN75976A1DGG SN75976A1DGGR	SN75976A1DL SN75976A1DLR	_
0°C to 70°C	4	5	SN75976A2DGG SN75976A2DGGR	SN75976A2DL SN75976A2DLR	_
–55°C to 125°C	8	9	—	—	SN55976A1WD
-55 C 10 125 C	4	5	_	_	SN55976A2WD

AVAILABLE OPTIONS

[†] The R suffix indicates taped and reeled packages.



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TERM	INAL	Logic	1/0	Tomination	DECODIDION
NAME	NO.	Level	1/0	Termination	DESCRIPTION
1A to 9A	4,6,8,10, 19,21,23, 25,27	TTL	I/O	Pullup	1A to 9A carry data to and from the communication controller.
1B- to 9B-	29,31,33, 35,37,.46, 48,50,52	RS-485	I/O	Pulldown	1B- to $9B-$ are the inverted data signals of the balanced pair to/from the bus.
1B+ to 9B+	30,32,34, 36,38,47, 49,51,53	RS-485	I/O	Pullup	1B+ to 9B+ are the noninverted data signals of the balanced pair to/from the bus.
BSR	2	TTL	Input	Pullup	BSR is the bit significant response. BSR disables receivers 1 through 8 and enables wired-OR drivers when BSR and DE/RE and CDE1 or CDE2 are high. Channel 9 is placed in a high-impedance state with BSR high.
CDE0	54	TTL	Input	Pulldown	CDE0 is the common driver enable 0. Its input signal enables all drivers when CDE0 and $1DE/RE - 9DE/RE$ are high.
CDE1	55	TTL	Input	Pulldown	CDE1 is the common driver enable 1. Its input signal enables drivers 1 to 4 when CDE1 is high and BSR is low.
CDE2	56	TTL	Input	Pulldown	CDE2 is the common driver enable 2. When CDE2 is high and BSR is low, drivers 5 to 8 are enabled.
CRE	3	TTL	Input	Pullup	CRE is the common receiver enable. When high, CRE disables receiver channels 5 to 9.
1DE/ <u>RE</u> to 9DE/RE	5,7,9,11, 20,22,24, 26,28	TTL	Input	Pullup	1DE/RE–9DE/RE are direction controls that transmit data to the bus when it and CDE0 are high. Data is received from the bus when 1DE/RE–9DE/RE and CRE and BSR are low and CDE1 and CDE2 are low.
GND	1,13,14, 15,16,17, 40,41,42, 43,44	NA	Power	NA	GND is the circuit ground. All GND terminals except terminal 1 are physically tied to the die pad for improved thermal conductivity.†
VCC	12,18,39, 45	NA	Power	NA	Supply voltage

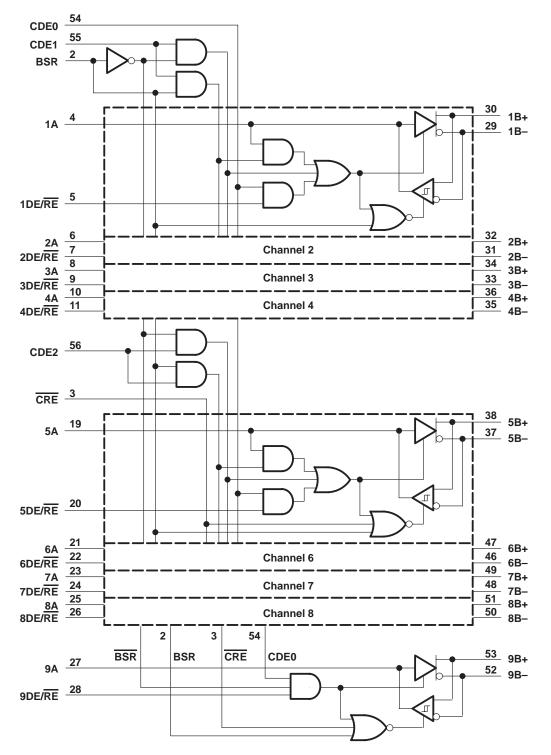
Terminal Functions

[†] Terminal 1 must be connected to signal ground for proper operation.



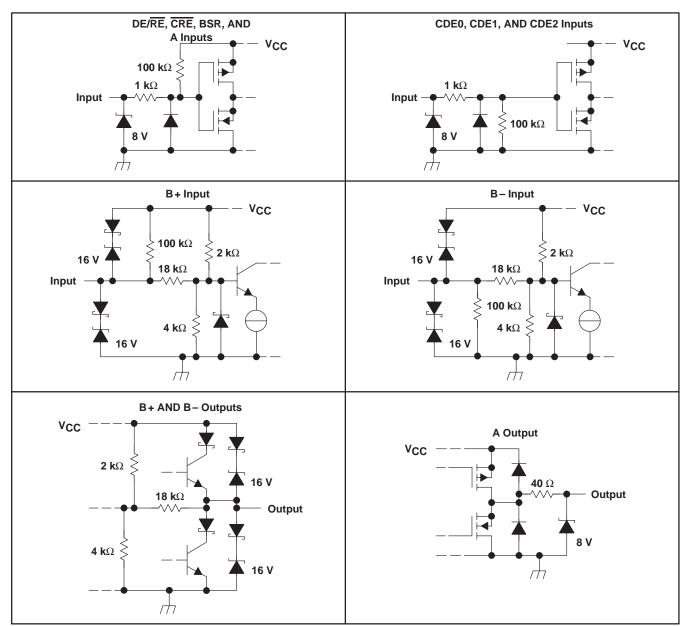
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logic diagram (positive logic)





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schematics of inputs and outputs



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} (see Note 1)Bus voltage range	
Data I/O and control (A side) voltage range –	
Electrostatic discharge: B side and GND, Class 3, A: (see Note 2)	12 kV
B side and GND, Class 3, B: (see Note 2)	400 V
All terminals, Class 3, A:	4 kV
All terminals, Class 3, B:	400 V
Continuous total power dissipation (see Note 3)	internally limited
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to the GND terminals.

2. This absolute maximum rating is tested in accordance with MIL-PRF-38535, Method 3015.7.

3. The maximum operating junction temperature is internally limited. Use the Dissipation Rating Table to operate below this temperature.

PACKAGE T _A ≤ 25°C		OPERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
DGG	2500 mW	20 mW/°C	1600 mW	—
DL	2500 mW	20 mW/°C	1600 mW	_
WD	1300 mW	10.5 mW/°C	827 mW	250 mW

DISSIPATION RATING TABLE

[‡]This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

package thermal characteristics

		MIN N	NOM	MAX	UNIT
Junction-to-ambient thermal resistance, R _{AJA}	DGG, board-mounted, no air flow		50		°C/W
Sunction-to-ambient thermal resistance, κ_{θ} JA	DL, board-mounted, no air flow		50		°C/W
Junction-to-ambient thermal resistance, $R_{\theta JA}$	WD		95.4		°C/W
Junction-to-case thermal resistance, R _{A.IC}	DGG		27		°C/W
	DL		12		°C/W
Junction-to-case thermal resistance, $R_{\theta JC}$	WD		5.67		°C/W
Thermal-shutdown junction temperature, T_{JS}			165		°C



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recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
High-level input voltage, VIH	Except nB+, nB-†	2			V
Low-level input voltage, VIL	Except nB+, nB-†			0.8	V
Voltage at any bus terminal (separately or common-mode), V _O , V _I , or V _{IC} High-level output current, I _{OH}	nPL or nP			12	V
				-7	V
High-level output current, I _{OH}	Driver			-60	mA
High-level output current, IOH	Receiver			-8	mA
	Except nB+, nB-† 2 Except nB+, nB-† 0.8 pr common-mode), V _O , V _I , or V _{IC} nB+ or nB - 12 Driver -77	mA			
	Receiver			8	mA
Operating case temperature, T _C	SN75976A	0		125	°C
	SN75976A	0		70	°C
	SN55976A	-55		125	°C

† n = 1 – 9



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	т,		TIONE	s	N55976/	۹.	S	N75976/	۹ (
	PARAMETER	11		TIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
		S1 to A,	V _T = 5 V,	See Figure 1	0.7			1	1.8		V
V _{IT+}	Driver differential high- level output voltage	S1 to B, T _C \ge 25°C		V _T = 5 V, See Figure 1				1	1.4		V
	lovol output voltago	S1 to B, See Figure 1		V _T = 5 V,	0.7			0.8			V
		S1 to A, T _C \ge 25°C		V _T = 5 V, See Figure 1	0.7	-1.4		-1	-1.4		V
Vodl	Driver differential low- level output voltage	S1 to B,	V _T = 5 V,	See Figure 1	0.7	-1.8		-1	-1.8		V
		S1 to A, See Figure 1		V _T = 5 V,	-0.8	-1.4		-0.8	-1.4		V
∨он	High-level output volt-	A side, I _{OH} = −8 mA		V _{ID} = 200 mV, See Figure 3	4	4.5		4	4.5		V
-	age	B side,	V _T = 5 V,	See Figure 1		3			3	MAX MAX MAX MAX MAX MAX MAX MAX MAX MAX	V
VOL	Low-level output volt-	A side, I _{OH} = 8 mA		V _{ID} = -200 mV, See Figure 3		0.6	0.8		0.6	0.8	V
	age	A side,	V _T = 5 V,	See Figure 1		1			1		V
V _{IT+}	Receiver positive-go- ing differential input threshold voltage	I _{OH} = -8 mA,		See Figure 3			0.2			0.2	V
VIT–	Receiver negative- going differential input threshold voltage	I _{OL} = 8 mA,		See Figure 3			-0.2			-0.2	V
V _{hys}	Receiver input hysteresis (VIT+- VIT-)	V _{CC} = 5 V,		$T_A = 25^{\circ}C$	24	45		24	45		mV
		V _{IH} = 12 V,	V _{CC} = 5 V,	Other input at 0 V		0.4	1		0.4	1	mA
I.	Due input ourrest	V _{IH} = 12 V,	V _{CC} = 0,	Other input at 0 V		0.5	1		0.5	1	mA
Ч	Bus input current	$V_{IH} = -7 V,$	V _{CC} = 5 V,	Other input at 0 V		-0.4	-0.8		-0.4	-0.8	mA
		$V_{IH} = -7 V,$	V _{CC} = 0,	Other input at 0 V		-0.3	-0.8		-0.3	-0.8	mA
I	High-level input cur-	A, BSR, DE/RE	, and CRE,	VIH = 2 V			-100			-100	μΑ
ЧН	rent	CDE0, CDE1, a	and CDE2,	$V_{IH} = 2V$			100			100	μΑ
L.,		A, BSR, DE/RE	, and CRE,	V _{IL} = 0.8 V			-100			-100	μΑ
ЧL	Low-level input current	CDE1, CDE1, a	and CDE2,	V _{IL} = 0.8 V			100			100	μA
los	Short circuit output current	nB+ or nB–					±260			±260	mA
	High-impedance-state	А			See	e I _{IH} and	۱ _{IL}	See	l _{IH} and	۱ _{IL}	
loz	output current	nB+ or nB–				See I _I			See I _I		
		Disabled					10			10	mA
ICC	Supply current	All drivers enab	oled, no load				60			60	mA
		All receivers en	abled, no loa	ad			45			45	mA
CO	Output capacitance	nB+ or nB– to 0	GND			18			18	25	pF
C _{pd}	Power dissipation capacitance	Receiver				40			40		pF
- pu	(see Note 4)	Driver				100			100		pF

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. NOTE 4: C_{pd} determines the no-load dynamic supply current consumption, I_S = C_{PD} × V_{CC} × f + I_{CC}



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			TEST	NDITIONS	S	N75976A		
	PARAMETER		TESTCO	ONDITIONS	MIN	TYP†	MAX	UNIT
					2.5		13.5	ns
		'976A1	V _{CC} = 5 V,	T _C = 25°C	3		11	ns
	Propagation delay time, tPHL or tPLH		V _{CC} = 5 V,	T _C = 100°C	5		13	ns
^t pd	(see Figures 1 and 2)				4.5		11.5	ns
		'976A2	V _{CC} = 5 V,	T _C = 25°C	5		9	ns
			V _{CC} = 5 V,	T _C = 100°C	7		11	ns
	Skew limit, maximum t _{pd} – minimum t _{pd}	'976A1					8	ns
^t sk(lim)	(see Note 5)	'976A2					4	ns
^t sk(p)	Pulse skew, t _{PHL} – t _{PLH}						4	ns
t _f	Fall time		S1 to B,	See Figure 2		4		ns
t _r	Rise time		See Figure 2			8		ns
t _{en}	Enable time, control inputs to active output						50	ns
t _{dis}	Disable time, control inputs to high-impedance or	utput					100	ns
^t PHZ	Propagation delay time, high-level to high-impeda	ance output				17	100	ns
^t PLZ	Propagation delay time, low-level to high-impeda	nce output				25	100	ns
tPZH	Propagation delay time, high-impedance to high-	level output	See Figures 5	and 6		17	50	ns
tPZL	Propagation delay time, high-impedance to low-le	evel output	1			17	50	ns

driver switching characteristics over recommended operating conditions (unless otherwise noted)

 $\overline{\dagger}$ All typical values are at V_{CC} = 5 V, T_A = 25°C.

NOTE 5: This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions and to any two devices.

driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CO	NDITIONS	S	N55976A	1	UNIT
	PARAMETER		TEST CO	MIN	TYP†	MAX	UNIT	
<u>،</u> .	Propagation delay time, tPHL or tPLH		V _{CC} = 5 V,	$T_A = 25^{\circ}C$			15	ns
^t pd	(see Figures 1 and 2)	'976A2	$V_{CC} = 5 V,$	$T_A = 25^{\circ}C$			13.5	ns
+ • <i>m</i> ×	Skew limit, maximum t _{pd} – minimum t _{pd} tsk(lim) (see Note 5)						8	ns
^t sk(lim)							4	ns
t _{sk(p)}	Pulse skew, tpHL - tpLH						4	ns
t _f	Fall time		S1 to B,	See Figure 2		4		ns
t _r	Rise time		See Figure 2			8		ns
ten	Enable time, control inputs to active output						60	ns
^t dis	Disable time, control inputs to high-impedance output	ut					140	ns
^t PHZ	Propagation delay time, high-level to high-impedanc	e output					120	ns
^t PLZ	Propagation delay time, low-level to high-impedance	output		and C			120	ns
^t PZH	Propagation delay time, high-impedance to high-leve	el output	See Figures 5	מווט ס			60	ns
t _{PZL}	Propagation delay time, high-impedance to low-level	loutput]				60	ns

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. NOTE 5. This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions and to any two devices.



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receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CO	NDITIONS	S	N75976A	1	UNIT
	PARAMETER			INDITIONS	MIN	TYP [†]	MAX	UNIT
		'976A1			7.5		16.5	ns
	Propagation delay time, tPHL or tPLH				8.5		14.5	ns
^t pd	(see Figures 3 and 4)	'976A2	V _{CC} = 5 V,	T _C = 25°C	8.6		13.6	ns
			V _{CC} = 5 V,	$T_{C} = 100^{\circ}C$	9		14	ns
• • • • •	Skew limit, maximum t _{pd} – minimum t _{pd}	'976A1					9	ns
^t sk(lim)	sk(lim) (see Note 5)	'976A2					5	ns
tsk(p)	Pulse skew, t _{PHL} – t _{PLH}					0.6	4	ns
tt	Transition time (t _r or t _f)		See Figure 4			2		ns
ten	Enable time, control inputs to active output						50	ns
^t dis	Disable time, control inputs to high-impedance outp	out					60	ns
^t PHZ	Propagation delay time, high-level to high-impedant	ce output					60	ns
^t PLZ	Propagation delay time, low-level to high-impedanc	e output		and Q			50	ns
^t PZH	Propagation delay time, high-impedance to high-lev	el output	See Figures 7	anu o			50	ns
^t PZL	Propagation delay time, high-impedance to low-leve	el output]				50	ns

[†] All typical values are at V_{CC} = 5 V, T_A = 25° C.

NOTE 5. This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions and to any two devices.

receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CO	NDITIONS	S	N55976/	۹.	UNIT
	PARAMETER	_	TESTCO	NDITIONS	MIN	TYP†	MAX	UNIT
÷ .	Propagation delay time, tPHL or tPLH	'976A1	$V_{CC} = 5 V,$	$T_A = 25^{\circ}C$			19	ns
^t pd	(see Figures 3 and 4)	'976A2	$V_{CC} = 5 V,$	$T_A = 25^{\circ}C$			16	ns
+	Skew limit, maximum t _{pd} – minimum t _{pd}	'976A1					9	ns
^t sk(lim)	(see Note 5)	'976A2					5	ns
t _{sk(p)}	Pulse skew, tpHL - tpLH				0.6	4	ns	
tt	Transition time (t _r or t _f)		See Figure 4			2		ns
t _{en}	Enable time, control inputs to active output						70	ns
t _{dis}	Disable time, control inputs to high-impedance output	ıt					80	ns
^t PHZ	Propagation delay time, high-level to high-impedance	e output					80	ns
^t PLZ	Propagation delay time, low-level to high-impedance		and 9		19 16 9 5 0.6 4 2 70 80			
^t PZH	Propagation delay time, high-impedance to high-leve	See Figures 7	anu o			70	ns	
^t PZL	Propagation delay time, high-impedance to low-level	output]				70	ns

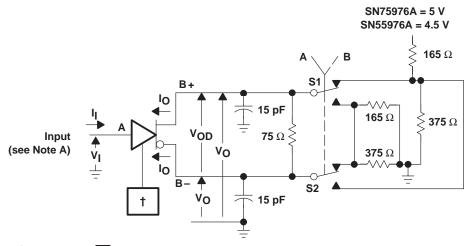
[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

NOTE 5. This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions and to any two devices.

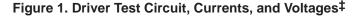


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PARAMETER MEASUREMENT INFORMATION



[†] CDE0 and DE/RE are at 2 V, BSR is at 0.8 V and, for the SN75976A only, all others are open. [‡] For the SN75976A only, all nine drivers are enabled, similarly loaded, and switching.



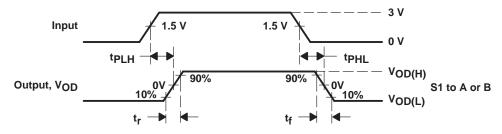
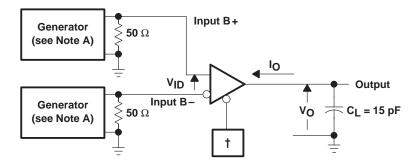


Figure 2. Driver Delay and Transition Time Test Waveforms



[†]CDE0, CDE1, CDE2, BSR, CRE, and DE/RE at 0.8 V [‡]For the SN75976A only, all nine receivers are enabled and switching.

Figure 3. Receiver Propagation Delay and Transition Time Test Circuit[‡]

- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_r \le 6$ ns, $t_f \le 6$ ns, $PRR \le 1$ MHz, duty cycle = 50%, $Z_O = 50 \Omega$.
 - B. All resistances are in Ω and \pm 5%, unless otherwise indicated.
 - C. All capacitances are in pF and \pm 10%, unless otherwise indicated.
 - D. All indicated voltages are \pm 10 mV.



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PARAMETER MEASUREMENT INFORMATION

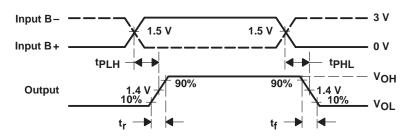
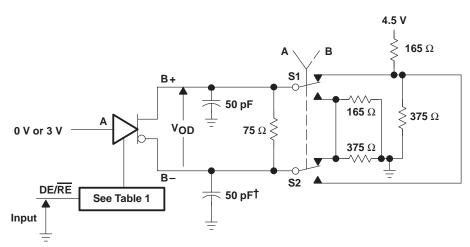


Figure 4. Receiver Delay and Transition Time Waveforms



[†] Includes probe and jig capacitance in two places.

Figure 5. Driver Enable and Disable Time Test Circuit

DRIVER	BSR	CDE0	CDE1	CDE2	CRE]
1 – 8	Н	Н	L	L	Х]
9	L	Н	Н	Н	Н	
	Input, DE/RE Output,	V _{OD} 0 V		¥ 0 V	V DD(H) A	at 3V 51 to B
	Output,	VOD				at 0V 51 to A

Table 1. Enabling For Driver Enable And Disable Time

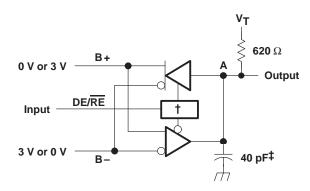
Figure 6. Driver Enable Time Waveforms

- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_f \le 6$ ns, $t_f \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50 \Omega$.
 - B. All resistances are in Ω and \pm 5%, unless otherwise indicated.
 - C. All capacitances are in pF and \pm 10%, unless otherwise indicated.
 - D. All indicated voltages are \pm 10 mV.



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PARAMETER MEASUREMENT INFORMATION



[†] CDE0 is high, CDE1, CDE2, BSR, and CRE are low and, for the SN75976A only, all others are open.

[‡] Includes probe and jig capacitance.

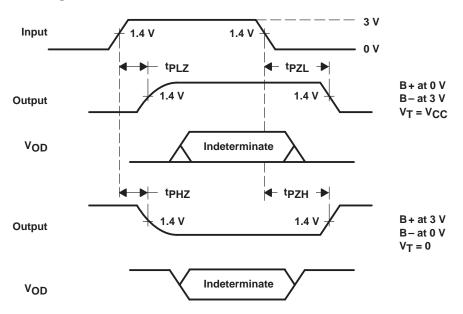


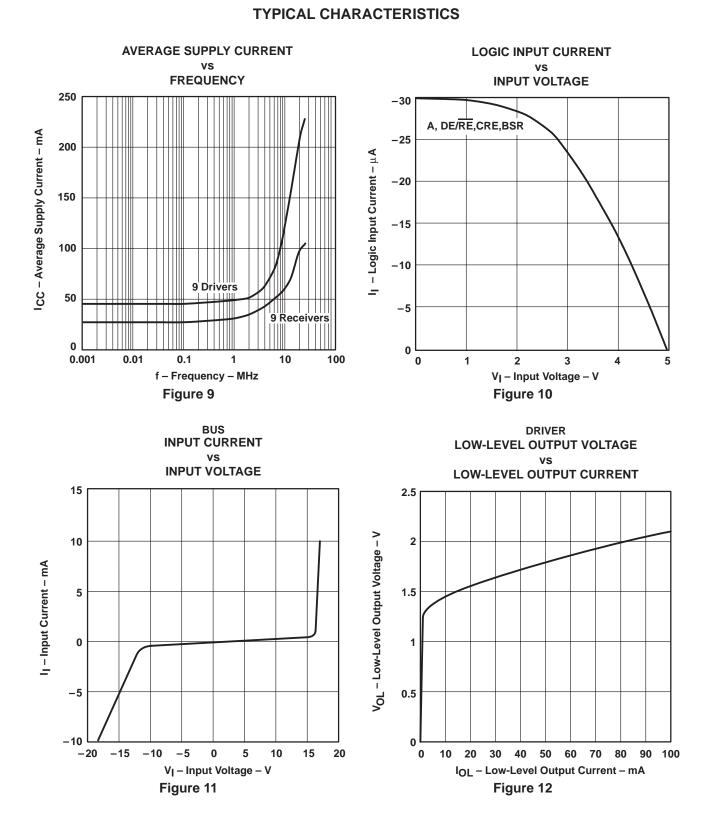
Figure 7. Receiver Enable and Disable Time Test Circuit

Figure 8. Receiver Enable and Disable Time Waveforms

- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_f \le 6$ ns, $t_f \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50 \Omega$.
 - B. All resistances are in Ω and \pm 5%, unless otherwise indicated.
 - C. All capacitances are in pF and \pm 10%, unless otherwise indicated.
 - D. All indicated voltages are \pm 10 mV.

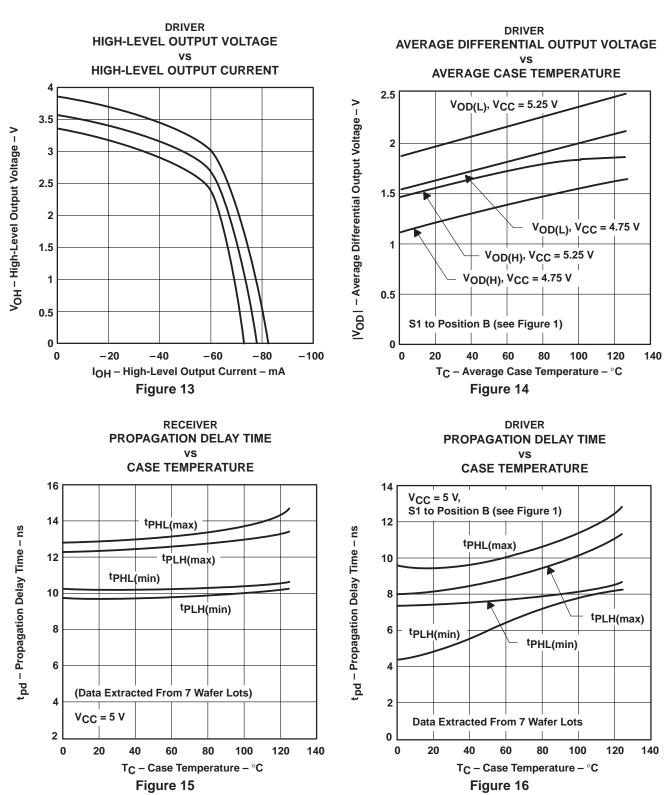


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SLLS218B - MAY 1995 - REVISED MAY 1997



TYPICAL CHARACTERISTICS



SLLS218B - MAY 1995 - REVISED MAY 1997

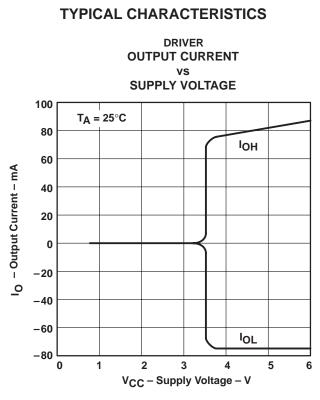


Figure 17



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APPLICATION INFORMATION

SIGNAL	TERMINAL	SCSI DATA	SCSI CONTROL	IPI DATA	IPI CONTROL
CDE0	54	DIFFSENSE	DIFFSENSE	VCC	Vcc
CDE1	55	GND	GND	XMTA, XMTB	GND
CDE2	56	GND	GND	XMTA, XMTB	SLAVE/MASTER
BSR	2	GND	GND	GND, BSR	GND
CRE	3	GND	GND	GND	V _{CC}
1A	4	DB0, DB8	ATN	AD7, BD7	NOT USED
1DE/RE	5	DBE0, DBE8	INIT EN	GND	GND
2A	6	DB1, DB9	BSY	AD6, BD6	NOT USED
2DE/RE	7	DBE1, DBE9	BSY EN	GND	GND
ЗA	8	DB2, DB10	ACK	AD5, BD5	SYNC IN
3DE/RE	9	DBE2, DBE10	INIT EN	GND	GND
4A	10	DB3, DB11	RST	AD4, BD4	SLAVE IN
4DE/RE	11	DBE3, DBE11	GND	GND	GND
5A	19	DB4, DB12	MSG	AD3, BD3	NOT USED
5DE/RE	20	DBE4, DBE12	TARG EN	GND	GND
6A	21	DB5, DB13	SEL	AD2, BD2	SYNC OUT
6DE/RE	22	DBE5, DBE13	SEL EN	GND	GND
7A	23	DB6, DB14	C/D	AD1, BD1	MASTER OUT
7DE/RE	24	DBE6, DBE14	TARG EN	GND	GND
8A	25	DB7, DB15	REQ	AD0, BD0	SELECT OUT
8DE/RE	26	DBE7, DBE15	TARG EN	GND	GND
9A	27	DBP0, DBP1	I/O	AP, BP	ATTENTION IN
9DE/RE	28	DBPE0, DBPE1	TARG EN	XMTA, XMTB	V _{CC}

Table 2. Typical Signal and Terminal Assignments

ABBREVIATIONS:

 $DBn = data bit n, where n = (0, 1, \dots, 15)$

DBEn = data bit n enable, where n = (0, 1, ..., 15)

DBP0 = parity bit for data bits 0 through 7 or IPI bus A

DBPE0 = parity bit enable for P0

DBP1 = parity bit for data bits 8 through 15 or IPI bus B

DBPE1 = parity bit enable for P1

ADn or BDn = IPI Bus A – Bit n (ADn) or Bus B – Bit n (BDn), where n = $(0,1,\ldots,7)$

AP or BP = IPI parity bit for bus A or bus B

XMTA or XMTB = transmit enable for IPI bus A or B

BSR = bit significant response

INIT EN = common enable for SCSI initiator mode

TARG EN = common enable for SCSI target mode

NOTE A: Signal inputs are shown as active high. When only active-low inputs are available, logic inversion is accomplished by reversing the B+ and B- connector terminal assignments.



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APPLICATION INFORMATION

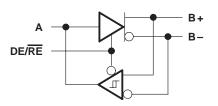
Function Tables





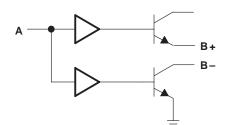
INP	INPUTS						
в+†	в_†	Α					
L	Н	L					
Н	L	н					

TRANSCEIVER



	INPU	ITS	OUTPUTS				
DE/RE	Α	в+†	в_†	Α	B+	В-	
L	-	L	Н	L	-	-	
L	_	Н	L	н	-	-	
н	L	-	-	-	L	н	
Н	Н	-	-	-	Н	L	

WIRED-OR DRIVER



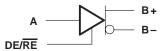
INPUT	OUTPUTS					
A	B+	В-				
L	Z	Ζ				
н	Н	L				

DRIVER



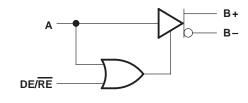
INPUT	OUTPUTS					
Α	B+	В-				
L	L	Н				
Н	н	L				

DRIVER WITH ENABLE



INPUT	'S	OUTPUTS				
DE/RE	Α	B+	В-			
L	L	Z	Z			
L	н	Z	Z			
Н	L	L	Н			
Н	Н	н	L			

TWO-ENABLE INPUT DRIVER



INPUT	ſS	OUTF	PUTS
DE/RE	Α	B+	В-
L	L	Z	Z
L	Н	н	L
н	L	L	Н
Н	Н	н	L

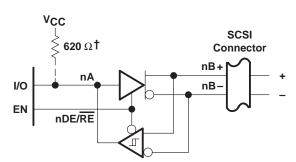
H = high level, L = low level, X = irrelevant, Z = high impedance (off)

[†] An H in this column represents a voltage of 200 mV or higher than the other bus input. An L represents a voltage of 200 mV or lower than the other bus input. Any voltage less than 200 mV results in an indeterminate receiver output.

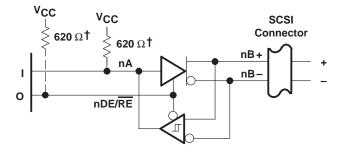


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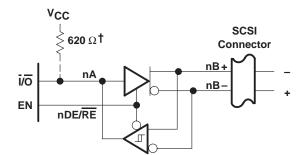
APPLICATION INFORMATION



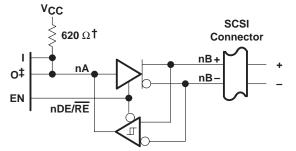




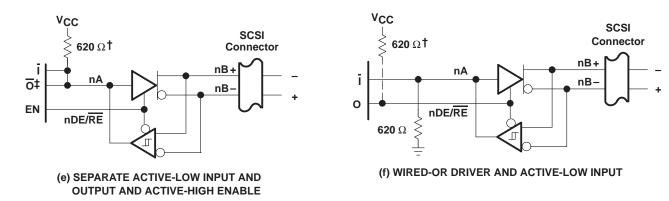
(c) WIRED-OR DRIVER AND ACTIVE-HIGH INPUT



(b) ACTIVE-LOW BIDIRECTIONAL I/O WITH SEPARATE ENABLE



(d) SEPARATE ACTIVE-HIGH INPUT, OUTPUT, AND ENABLE



[†]When 0 is open drain

[‡] Must be open-drain or 3-state output

NOTE A: The BSR, CRE, A, and DE/RE inputs have internal pullup resistors. CDE0, CDE1, and CDE2 have internal pulldown resistors.

Figure 18. Typical SCSI Transceiver Connections



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APPLICATION INFORMATION

channel logic configurations with control input logic

The following logic diagrams show the positive-logic representation for all combinations of control inputs. The control inputs are from MSB to LSB; the BSR, CDE0, CDE1, CDE2, and CRE bit values are shown below the diagrams. Channel 1 is at the top of the logic diagrams; channel 9 is at the bottom of the logic diagrams.

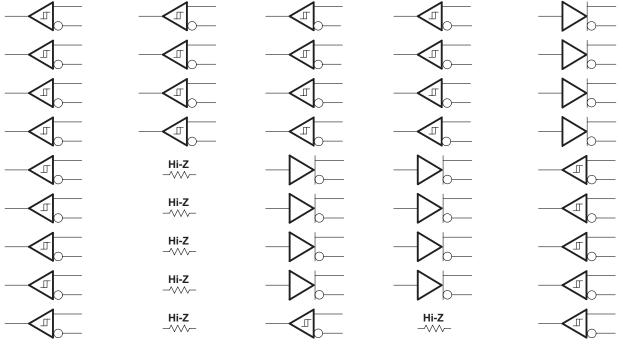


Figure 19. 00000

Figure 20. 00001

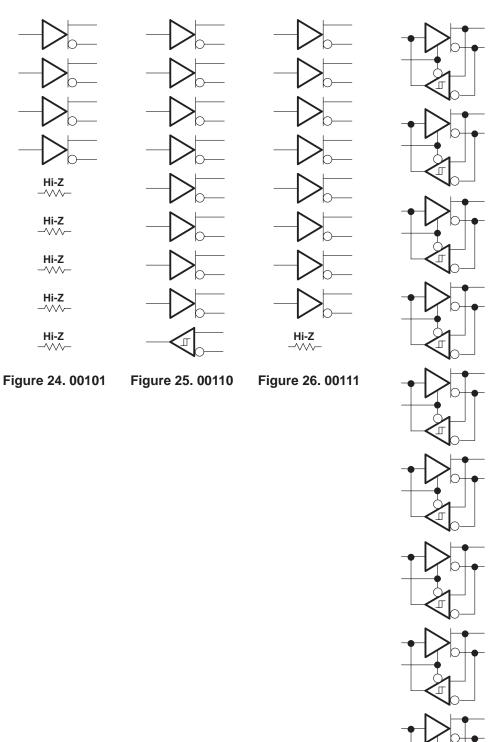
Figure 21. 00010

Figure 22. 00011

Figure 23. 00100



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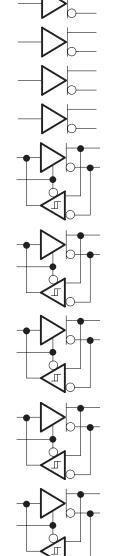
APPLICATION INFORMATION

Figure 28. 01001



Figure 27. 01000

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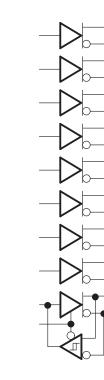


Figure 32. 01101

Figure 33. 01110

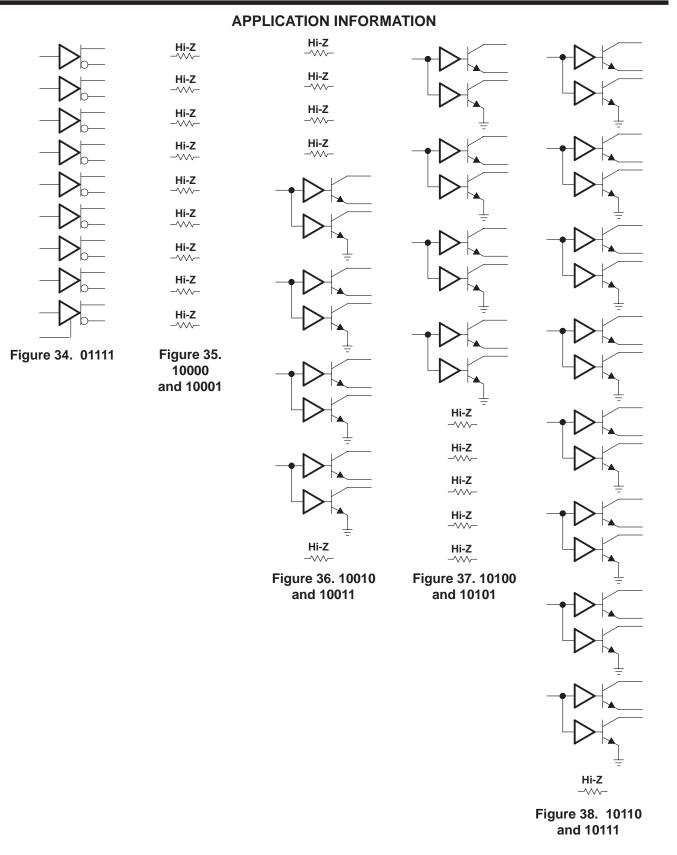
Figure 29. 01010

Figure 30. 01011





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APPLICATION INFORMATION

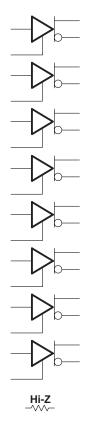


Figure 39. 11000 and 11001

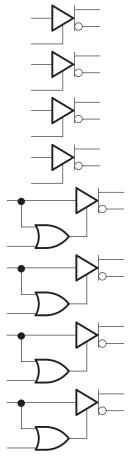




Figure 40. 11010 and 11011 Figure 41. 11100 and 11101

Hi-Z

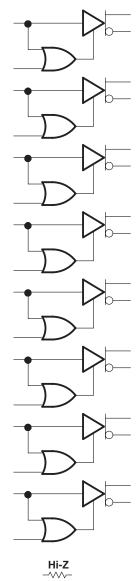


Figure 42. 11110

and 11111

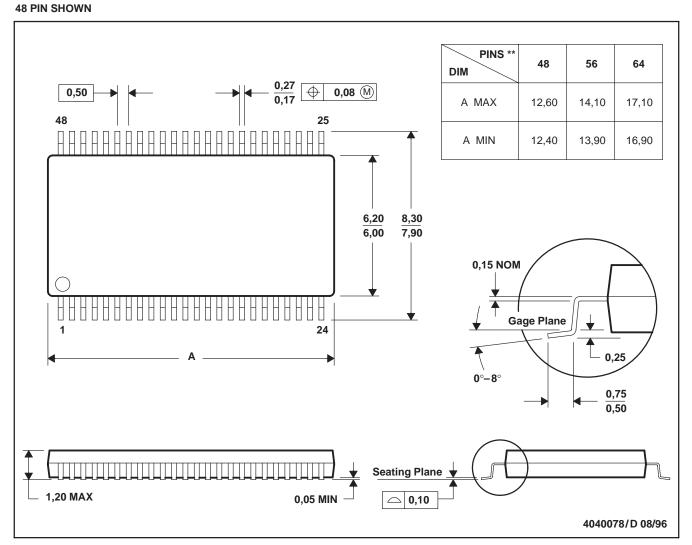


SLLS218B - MAY 1995 - REVISED MAY 1997

MECHANICAL INFORMATION

PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G**)



NOTES: B. All linear dimensions are in millimeters.

C. This drawing is subject to change without notice.

D. Falls within JEDEC MO-153



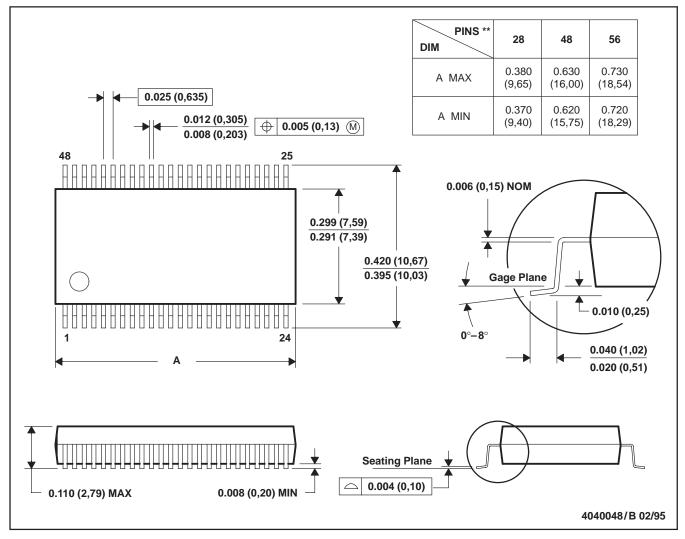
SLLS218B - MAY 1995 - REVISED MAY 1997

MECHANICAL INFORMATION

DL (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).



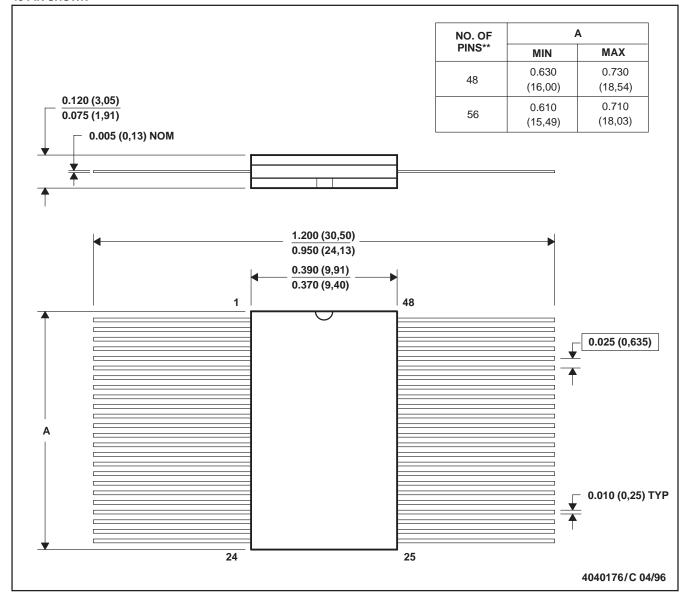
SLLS218B - MAY 1995 - REVISED MAY 1997

MECHANICAL INFORMATION

CERAMIC DUAL FLATPACK

48 PIN SHOWN

WD (R-GDFP-F**)



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for pin identification only
- E. Falls within MIL-STD-1835: GDFP1-F48 and JEDEC MO -146AA GDFP1-F56 and JEDEC MO -146AB





25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9689301QXA	ACTIVE	CFP	WD	56	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9689301QX A SNJ55976A1WD	Samples
SN55976A1WD	ACTIVE	CFP	WD	56	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN55976A1WD	Samples
SN75976A1DGG	ACTIVE	TSSOP	DGG	56	35	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A1DGGG4	ACTIVE	TSSOP	DGG	56	35	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A1DGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	SN75976A1	Samples
SN75976A1DGGRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	SN75976A1	Samples
SN75976A1DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A1DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A1DLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A1DLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A1	Samples
SN75976A2DGG	ACTIVE	TSSOP	DGG	56	35	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	SN75976A2	Samples
SN75976A2DGGG4	ACTIVE	TSSOP	DGG	56	35	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	SN75976A2	Samples
SN75976A2DGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples
SN75976A2DGGRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples
SN75976A2DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples
SN75976A2DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples
SN75976A2DLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples



25-Sep-2013

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN75976A2DLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR		SN75976A2	Samples
SNJ55976A1WD	ACTIVE	CFP	WD	56	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9689301QX A SNJ55976A1WD	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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OTHER QUALIFIED VERSIONS OF SN55976A, SN75976A :



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PACKAGE OPTION ADDENDUM

25-Sep-2013

Catalog: SN75976A

• Enhanced Product: SN75976A-EP, SN75976A-EP

Military: SN55976A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



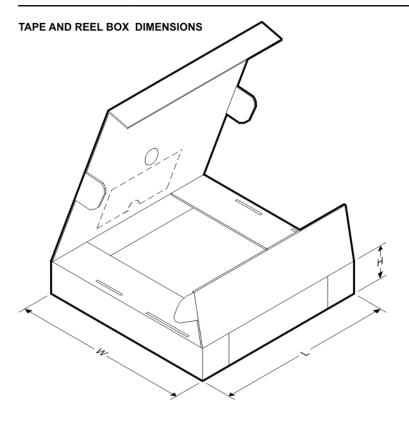
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75976A1DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN75976A1DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
SN75976A2DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN75976A2DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75976A1DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN75976A1DLR	SSOP	DL	56	1000	367.0	367.0	55.0
SN75976A2DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN75976A2DLR	SSOP	DL	56	1000	367.0	367.0	55.0

MECHANICAL DATA

MCFP010B - JANUARY 1995 - REVISED NOVEMBER 1997

CERAMIC DUAL FLATPACK

WD (R-GDFP-F**)

48 LEADS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only
 - E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA
 - GDFP1-F56 and JEDEC MO-146AB



DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice. В.
 - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
 - D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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